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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Discontinued at Digi-Key
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I ² C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	82
Program Memory Size	96KB (96K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	12K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 20x8/10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104pfafv0

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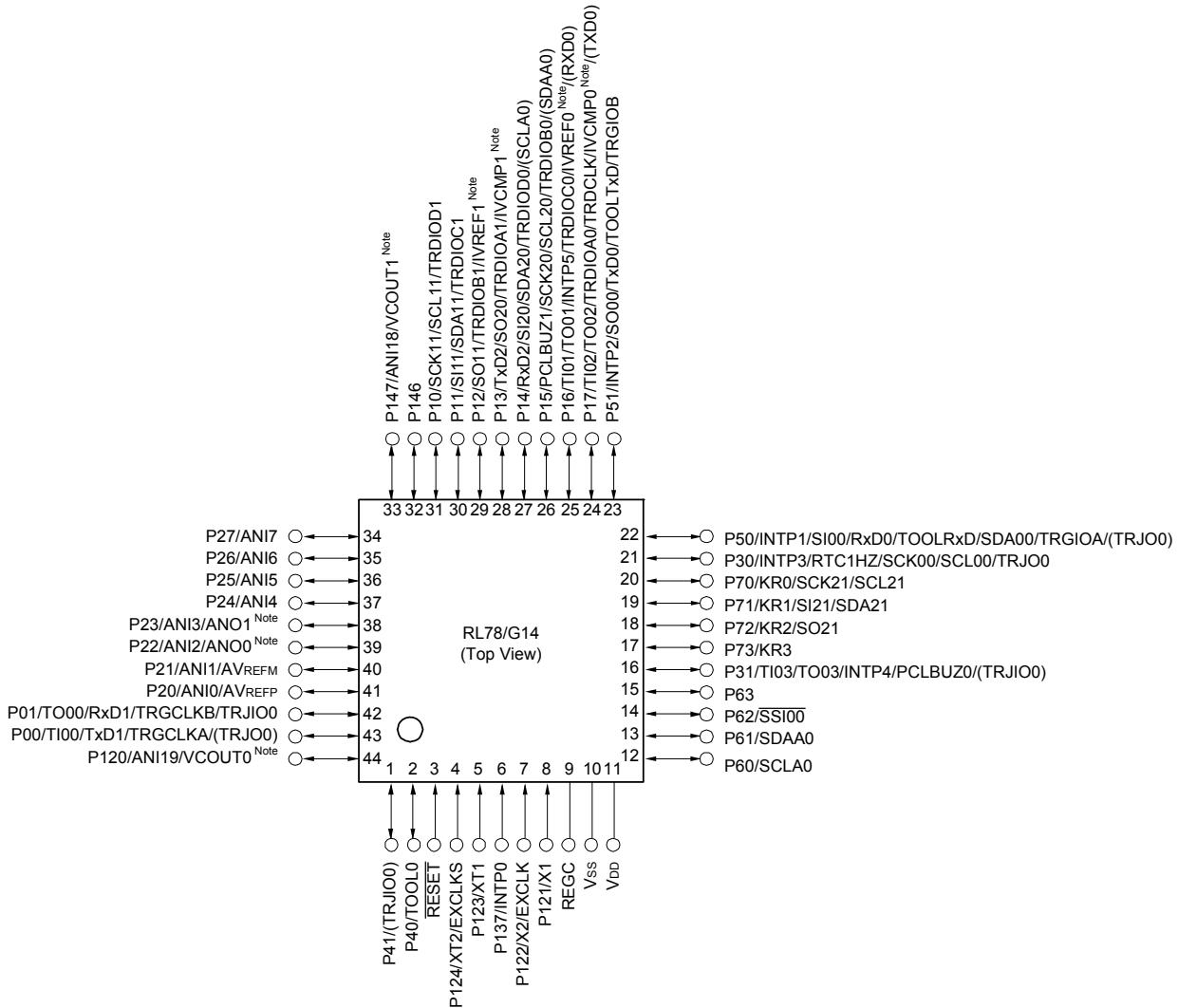
Pin count	Package	Fields of Application Note	Ordering Part Number
40 pins	40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch)	A	R5F104EAANA#U0, R5F104ECANA#U0, R5F104EDANA#U0, R5F104EEANA#U0, R5F104EFANA#U0, R5F104EGANA#U0, R5F104EHANA#U0 R5F104EAANA#W0, R5F104ECANA#W0, R5F104EDANA#W0, R5F104EEANA#W0, R5F104EFANA#W0, R5F104EGANA#W0, R5F104EHANA#W0
		D	R5F104EADNA#U0, R5F104ECDNA#U0, R5F104EDDNA#U0, R5F104EEDNA#U0, R5F104EFDNA#U0, R5F104EGDNA#U0, R5F104EHDNA#U0 R5F104EADNA#W0, R5F104ECDNA#W0, R5F104EDDNA#W0, R5F104EEDNA#W0, R5F104EFDNA#W0, R5F104EGDNA#W0, R5F104EHDNA#W0
		G	R5F104EAGNA#U0, R5F104ECGNA#U0, R5F104EDGNA#U0, R5F104EEGNA#U0, R5F104EFGNA#U0, R5F104EGGNA#U0, R5F104EHGNA#U0 R5F104EAGNA#W0, R5F104ECGNA#W0, R5F104EDGNA#W0, R5F104EEGNA#W0, R5F104EFGNA#W0, R5F104EGGNA#W0, R5F104EHGNA#W0
44 pins	44-pin plastic LQFP (10 × 10, 0.8 mm pitch)	A	R5F104FAAFP#V0, R5F104FC AFP#V0, R5F104FDAFP#V0, R5F104FEA FP#V0, R5F104FFA FP#V0, R5F104FG AFP#V0, R5F104FH AFP#V0, R5F104FJA FP#V0 R5F104FAAFP#X0, R5F104FC AFP#X0, R5F104FDAFP#X0, R5F104FEA FP#X0, R5F104FFA FP#X0, R5F104FG AFP#X0, R5F104FH AFP#X0, R5F104FJA FP#X0
		D	R5F104FADFP#V0, R5F104FCDFP#V0, R5F104FDDFP#V0, R5F104FEDFP#V0, R5F104FFDFP#V0, R5F104FGDFP#V0, R5F104FHDFP#V0, R5F104FJD FP#V0 R5F104FADFP#X0, R5F104FCDFP#X0, R5F104FDDFP#X0, R5F104FEDFP#X0, R5F104FFDFP#X0, R5F104FGDFP#X0, R5F104FHDFP#X0, R5F104FJD FP#X0
		G	R5F104FAGFP#V0, R5F104FC GFP#V0, R5F104FD GFP#V0, R5F104FEGFP#V0, R5F104FF GFP#V0, R5F104FG GFP#V0, R5F104FH GFP#V0, R5F104FJ GFP#V0 R5F104FAGFP#X0, R5F104FC GFP#X0, R5F104FD GFP#X0, R5F104FEGFP#X0, R5F104FF GFP#X0, R5F104FG GFP#X0, R5F104FH GFP#X0, R5F104FJ GFP#X0

Note For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3.5 44-pin products

- 44-pin plastic LQFP (10 × 10 mm, 0.8 mm pitch)



Note Mounted on the 96 KB or more code flash memory products.

Caution Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μ F).

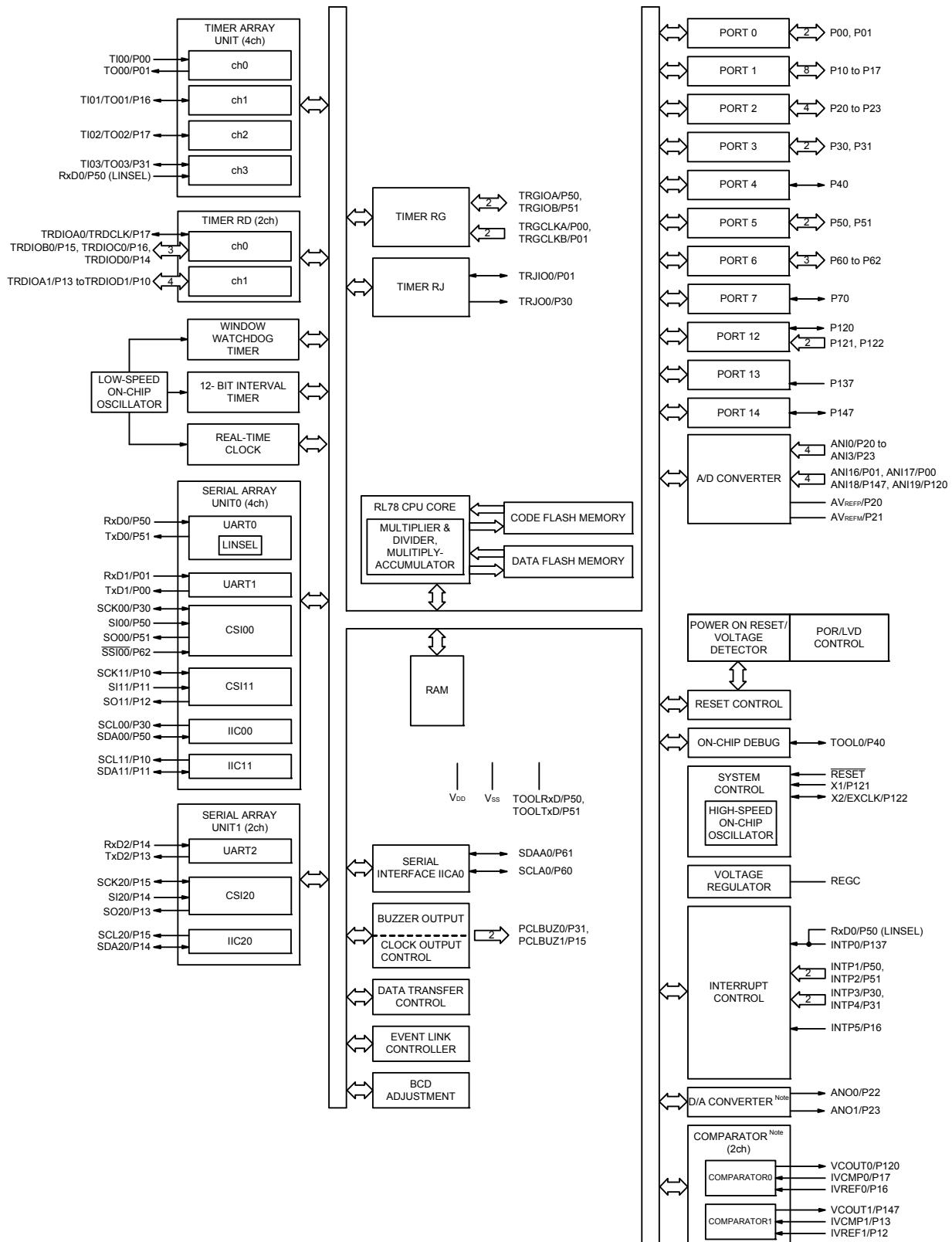
Remark 1. For pin identification, see **1.4 Pin Identification**.

Remark 2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

1.4 Pin Identification

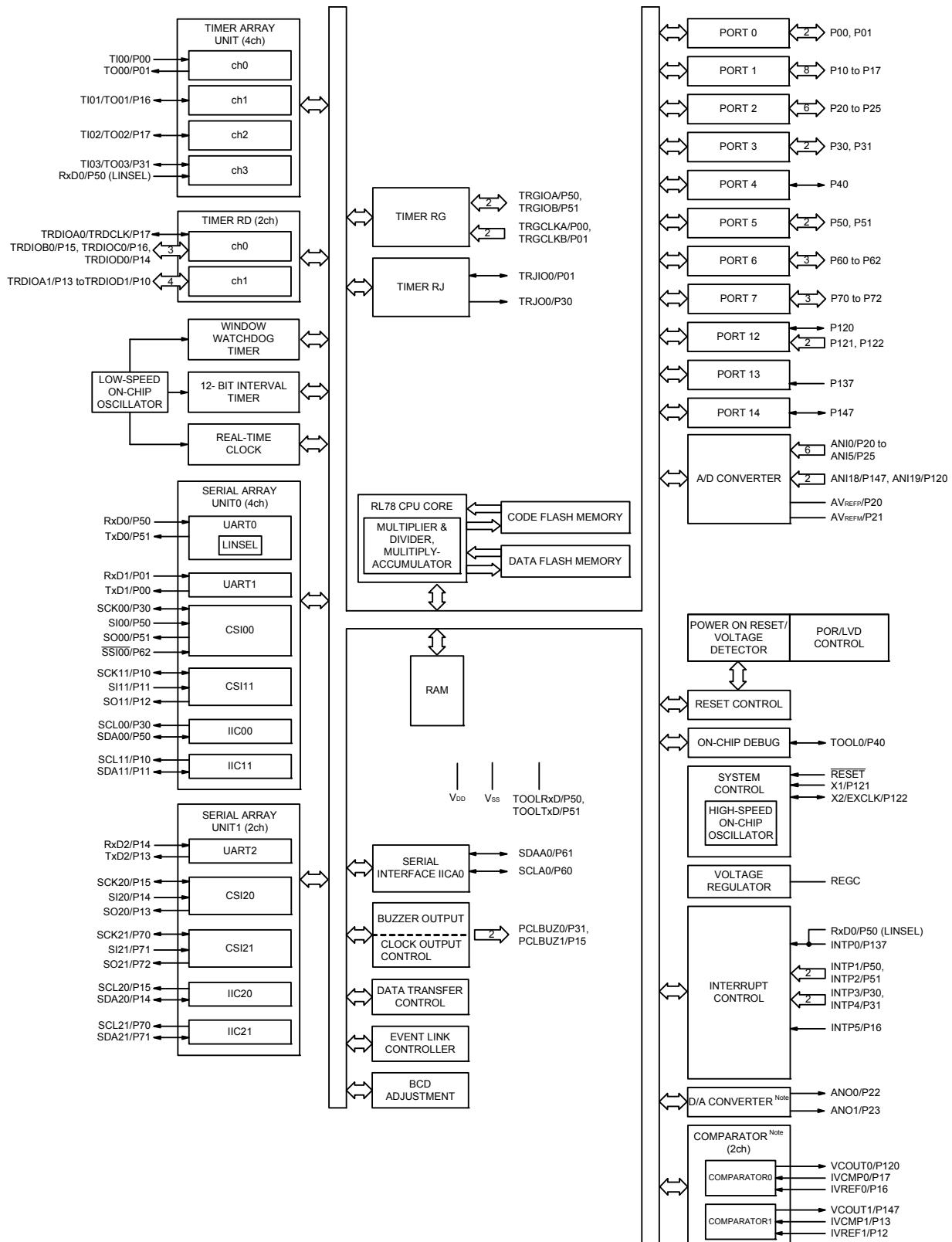
ANIO to ANI14,: ANI16 to ANI20 ANO0, ANO1: AVREFM: AVREFP: EVDD0, EVDD1: EVSS0, EVSS1: EXCLK: EXCLKS: INTP0 to INTP11: IVCMP0, IVCMP1: IVREF0, IVREF1: KR0 to KR7: P00 to P06: P10 to P17: P20 to P27: P30, P31: P40 to P47: P50 to P57: P60 to P67: P70 to P77: P80 to P87: P100 to P102: P110, P111: P120 to P124: P130, P137: P140 to P147: P150 to P156: PCLBUZ0, PCLBUZ1: REGC: RESET: RTC1HZ:	Analog input Analog output A/D converter reference potential (– side) input A/D converter reference potential (+ side) input Power supply for port Ground for port External clock input (main system clock) External clock input (subsystem clock) External interrupt input Comparator input Comparator reference input Key return Port 0 Port 1 Port 2 Port 3 Port 4 Port 5 Port 6 Port 7 Port 8 Port 10 Port 11 Port 12 Port 13 Port 14 Port 15 Programmable clock output/buzzer output Regulator capacitance Reset Real-time clock correction clock (1 Hz) output	RxD0 to RxD3: SCK00, SCK01, SCK10,: SCK11, SCK20, SCK21, SCK30, SCK31 SCLA0, SCLA1,: SCL00, SCL01, SCL10, SCL11,: SCL20, SCL21, SCL30, SCL31 SDAA0, SDAA1, SDA00,: SDA01, SDA10, SDA11, SDA20, SDA21, SDA30, SDA31 SI00, SI01, SI10, SI11,: SI20, SI21, SI30, SI31 SO00, SO01, SO10,: SO11, SO20, SO21, SO30, SO31 <u>SSI00</u> : TI00 to TI03,: TI10 to TI13 TO00 to TO03,: TO10 to TO13, TRJ00 TOOL0: TOOLRxD, TOOLTxD: TRDCLK, TRGCLKA,: TRGCLKB TRDIOA0, TRDIOB0,: TRDIOC0, TRDIOD0, TRDIOA1, TRDIOB1, TRDIOC1, TRDIOD1, TRGIOA, TRGIOB, TRJ00 TxD0 to TxD3: VCOUT0, VCOUT1: VDD: Vss: X1, X2: XT1, XT2:	Receive data Serial clock input/output Serial clock input/output Serial clock output Serial data input/output Serial data output Serial data input Serial interface chip select input Timer input Timer output Data input/output for tool Data input/output for external device Timer external input clock Timer input/output Transmit data Comparator output Power supply Ground Crystal oscillator (main system clock) Crystal oscillator (subsystem clock)
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1.5.2 32-pin products



Note Mounted on the 96 KB or more code flash memory products.

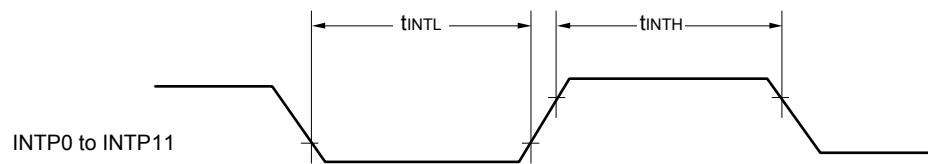
1.5.3 36-pin products



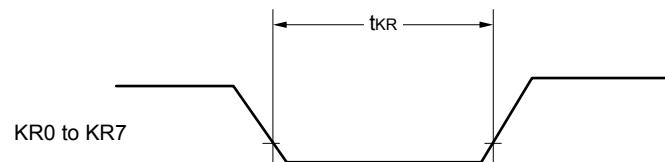
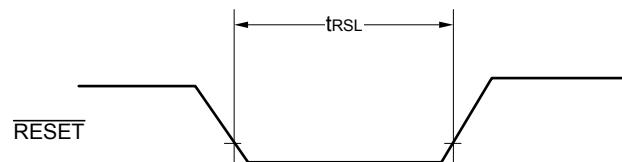
Note Mounted on the 96 KB or more code flash memory products.

- Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.
The target products and start address of the RAM areas used by the flash library are shown below.
R5F104xJ (x = F, G, J, L, M, P): Start address F9F00H
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

Interrupt Request Input Timing



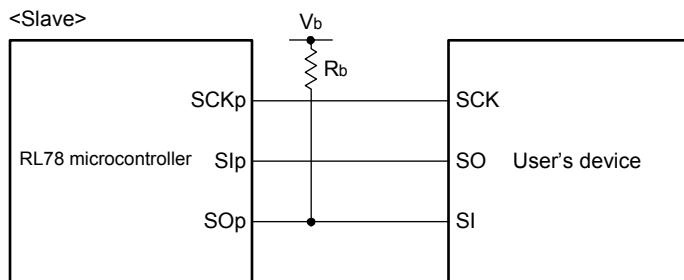
Key Interrupt Input Timing

RESET Input Timing

- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** Use it with EV_{DD0} ≥ V_b.
- Note 3.** When DAP_{Mn} = 0 and CKP_{Mn} = 0, or DAP_{Mn} = 1 and CKP_{Mn} = 1. The S_{lp} setup time becomes “to SCKp↓” when DAP_{Mn} = 0 and CKP_{Mn} = 1, or DAP_{Mn} = 1 and CKP_{Mn} = 0.
- Note 4.** When DAP_{Mn} = 0 and CKP_{Mn} = 0, or DAP_{Mn} = 1 and CKP_{Mn} = 1. The S_{lp} hold time becomes “from SCKp↓” when DAP_{Mn} = 0 and CKP_{Mn} = 1, or DAP_{Mn} = 1 and CKP_{Mn} = 0.
- Note 5.** When DAP_{Mn} = 0 and CKP_{Mn} = 0, or DAP_{Mn} = 1 and CKP_{Mn} = 1. The delay time to SO_{Op} output becomes “from SCKp↑” when DAP_{Mn} = 0 and CKP_{Mn} = 1, or DAP_{Mn} = 1 and CKP_{Mn} = 0.

Caution Select the TTL input buffer for the S_{lp} pin and SCKp pin, and the N-ch open drain output (V_{DD} tolerance (for the 30- to 52-pin products)/EV_{DD} tolerance (for the 64- to 100-pin products)) mode for the SO_{Op} pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)



Remark 1. R_b[Ω]: Communication line (SO_{Op}) pull-up resistance, C_b[F]: Communication line (SO_{Op}) load capacitance, V_b[V]: Communication line voltage

Remark 2. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

Remark 3. fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSm_n bit of serial mode register mn (SMR_{Mn}).

m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))

Remark 4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

2.6 Analog Characteristics

2.6.1 A/D converter characteristics

Classification of A/D converter characteristics

Input channel	Reference Voltage Reference voltage (+) = AVREFP Reference voltage (-) = AVREFM	Reference voltage (+) = VDD Reference voltage (-) = VSS	Reference voltage (+) = VBGR Reference voltage (-) = AVREFM
AN10 to AN14	Refer to 2.6.1 (1).	Refer to 2.6.1 (3).	Refer to 2.6.1 (4). —
AN16 to AN20	Refer to 2.6.1 (2).		
Internal reference voltage Temperature sensor output voltage	Refer to 2.6.1 (1).		

- (1) When reference voltage (+) = AVREFP/AN10 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AVREFM/AN11 (ADREFM = 1), target pin: AN12 to AN14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ AVREFP ≤ VDD ≤ 5.5 V, VSS = 0 V, Reference voltage (+) = AVREFP, Reference voltage (-) = AVREFM = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error Note 1	AINL	10-bit resolution AVREFP = VDD Note 3	1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4	1.2 1.2	±3.5 ±7.0	LSB
Conversion time	tconv	10-bit resolution Target pin: AN12 to AN14	3.6 V ≤ VDD ≤ 5.5 V 2.7 V ≤ VDD ≤ 5.5 V 1.8 V ≤ VDD ≤ 5.5 V 1.6 V ≤ VDD ≤ 5.5 V	2.125 3.1875 17 57	39 39 39 95	μs
			3.6 V ≤ VDD ≤ 5.5 V 2.7 V ≤ VDD ≤ 5.5 V 1.8 V ≤ VDD ≤ 5.5 V 1.6 V ≤ VDD ≤ 5.5 V	2.375 3.5625 17	39 39 39	μs
			3.6 V ≤ VDD ≤ 5.5 V 2.7 V ≤ VDD ≤ 5.5 V 1.8 V ≤ VDD ≤ 5.5 V 1.6 V ≤ VDD ≤ 5.5 V	2.375 3.5625 17	39 39 39	μs
			3.6 V ≤ VDD ≤ 5.5 V 2.7 V ≤ VDD ≤ 5.5 V 1.8 V ≤ VDD ≤ 5.5 V 1.6 V ≤ VDD ≤ 5.5 V	2.375 3.5625 17	39 39 39	μs
	Ezs	10-bit resolution AVREFP = VDD Note 3	1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±0.25 ±0.50	%FSR
			1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±0.25 ±0.50	%FSR
	Efs	10-bit resolution AVREFP = VDD Note 3	1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±0.25 ±0.50	%FSR
			1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±0.25 ±0.50	%FSR
Integral linearity error Note 1	ILE	10-bit resolution AVREFP = VDD Note 3	1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±2.5 ±5.0	LSB
			1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±2.5 ±5.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution AVREFP = VDD Note 3	1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±1.5 ±2.0	LSB
			1.8 V ≤ AVREFP ≤ 5.5 V 1.6 V ≤ AVREFP ≤ 5.5 V Note 4		±1.5 ±2.0	LSB
Analog input voltage	VAIN	AN12 to AN14	0		AVREFP	V
		Internal reference voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode)			VBGR Note 5	V
		Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode)			VTMP25 Note 5	V

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. When AVREFP < VDD, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AVREFP = VDD.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AVREFP = VDD.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AVREFP = VDD.

Note 4. Values when the conversion time is set to 57 μs (min.) and 95 μs (max.).

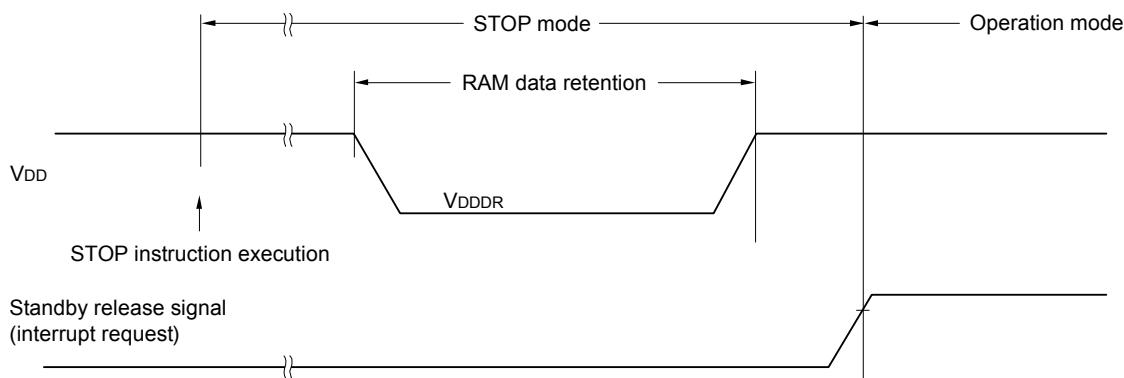
Note 5. Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

2.7 RAM Data Retention Characteristics

(TA = -40 to +85°C, Vss = 0V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.46 Note		5.5	V

Note The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.



2.8 Flash Memory Programming Characteristics

(TA = -40 to +85°C, 1.8 V ≤ VDD ≤ 5.5 V, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	fCLK	1.8 V ≤ VDD ≤ 5.5 V	1		32	MHz
Number of code flash rewrites Notes 1, 2, 3	Cerwr	Retained for 20 years TA = 85°C	1,000			Times
Number of data flash rewrites Notes 1, 2, 3		Retained for 1 year TA = 25°C		1,000,000		
		Retained for 5 years TA = 85°C	100,000			
		Retained for 20 years TA = 85°C	10,000			

Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

Note 2. When using flash memory programmer and Renesas Electronics self-programming library

Note 3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

2.9 Dedicated Flash Memory Programmer Communication (UART)

(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, Vss = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

Operation of products rated “G: Industrial applications (TA = -40 to + 105°C)” at ambient operating temperatures above 85°C differs from that of products rated “A: Consumer applications” and “D: Industrial applications” in the ways listed below.

Parameter	A: Consumer applications, D: Industrial applications	G: Industrial applications
Operating ambient temperature	TA = -40 to +85°C	TA = -40 to +105°C
Operating mode Operating voltage range	HS (high-speed main) mode: 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz LS (low-speed main) mode: 1.8 V ≤ VDD ≤ 5.5 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V ≤ VDD ≤ 5.5 V@1 MHz to 4 MHz	HS (high-speed main) mode only: 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz
High-speed on-chip oscillator clock accuracy	1.8 V ≤ VDD ≤ 5.5 V: ±1.0% @ TA = -20 to +85°C ±1.5% @ TA = -40 to -20°C 1.6 V ≤ VDD < 1.8 V: ±5.0% @ TA = -20 to +85°C ±5.5% @ TA = -40 to -20°C	2.4 V ≤ VDD ≤ 5.5 V: ±2.0% @ TA = +85 to +105°C ±1.0% @ TA = -20 to +85°C ±1.5% @ TA = -40 to -20°C
Serial array unit	UART CSI: fCLK/2 (16 Mbps supported), fCLK/4 Simplified I ² C communication	UART CSI: fCLK/4 Simplified I ² C communication
IICA	Standard mode Fast mode Fast mode plus	Standard mode Fast mode
Voltage detector	• Rising: 1.67 V to 4.06 V (14 stages) • Falling: 1.63 V to 3.98 V (14 stages)	• Rising: 2.61 V to 4.06 V (8 stages) • Falling: 2.55 V to 3.98 V (8 stages)

Remark The electrical characteristics of products rated “G: Industrial applications (TA = -40 to + 105°C)” at ambient operating temperatures above 85°C differ from those of products rated “A: Consumer applications” and “D: Industrial applications”. For details, refer to **3.1** to **3.10**.

- Note 1.** Total current flowing into V_{DD}, EV_{DD0}, and EV_{DD1}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, EV_{DD0}, and EV_{DD1}, or V_{SS}, EV_{VSS0}, and EV_{VSS1}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
HS (high-speed main) mode: 2.7 V ≤ V_{DD} ≤ 5.5 V@1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 5.5 V@1 MHz to 16 MHz

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{HOCO}: High-speed on-chip oscillator clock frequency (64 MHz max.)

Remark 3. f_H: High-speed on-chip oscillator clock frequency (32 MHz max.)

Remark 4. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

Remark 5. Except subsystem clock operation, temperature condition of the TYP. value is T_A = 25°C

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(3) Flash ROM: 384 to 512 KB of 48- to 100-pin products

(TA = -40 to +105°C, 2.4 V ≤ EV_{D0} = EV_{D1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{S0} = EV_{S1} = 0 V)

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current Note 1	I _{DD2} Note 2	HALT mode HS (high-speed main) mode Note 7	f _{HOCO} = 64 MHz, f _{IH} = 32 MHz Note 4	V _{DD} = 5.0 V		0.93	5.16		mA
				V _{DD} = 3.0 V		0.93	5.16		
			f _{HOCO} = 32 MHz, f _{IH} = 32 MHz Note 4	V _{DD} = 5.0 V		0.5	4.47		
				V _{DD} = 3.0 V		0.5	4.47		
			f _{HOCO} = 48 MHz, f _{IH} = 24 MHz Note 4	V _{DD} = 5.0 V		0.72	4.08		
				V _{DD} = 3.0 V		0.72	4.08		
			f _{HOCO} = 24 MHz, f _{IH} = 24 MHz Note 4	V _{DD} = 5.0 V		0.42	3.51		
				V _{DD} = 3.0 V		0.42	3.51		
			f _{HOCO} = 16 MHz, f _{IH} = 16 MHz Note 4	V _{DD} = 5.0 V		0.39	2.38		
				V _{DD} = 3.0 V		0.39	2.38		
			HS (high-speed main) mode Note 7	f _{MX} = 20 MHz Note 3, V _{DD} = 5.0 V	Square wave input	0.31	2.83		mA
					Resonator connection	0.41	2.92		
				f _{MX} = 20 MHz Note 3, V _{DD} = 3.0 V	Square wave input	0.31	2.83		
					Resonator connection	0.41	2.92		
				f _{MX} = 10 MHz Note 3, V _{DD} = 5.0 V	Square wave input	0.21	1.46		
					Resonator connection	0.26	1.57		
			Subsystem clock operation	f _{SUB} = 32.768 kHz Note 5, TA = -40°C	Square wave input	0.31	0.76		μA
					Resonator connection	0.50	0.95		
				f _{SUB} = 32.768 kHz Note 5, TA = +25°C	Square wave input	0.38	0.76		
					Resonator connection	0.57	0.95		
				f _{SUB} = 32.768 kHz Note 5, TA = +50°C	Square wave input	0.47	3.59		
					Resonator connection	0.70	3.78		
			f _{SUB} = 32.768 kHz Note 5, TA = +70°C	f _{SUB} = 32.768 kHz Note 5, TA = +70°C	Square wave input	0.80	6.20		μA
					Resonator connection	1.00	6.39		
				f _{SUB} = 32.768 kHz Note 5, TA = +85°C	Square wave input	1.65	10.56		
					Resonator connection	1.84	10.75		
				f _{SUB} = 32.768 kHz Note 5, TA = +105°C	Square wave input	8.00	65.7		
					Resonator connection	8.00	65.7		
			I _{DD3} Note 6	STOP mode Note 8	TA = -40°C		0.19	0.63	μA
					TA = +25°C		0.30	0.63	
					TA = +50°C		0.41	3.47	
					TA = +70°C		0.80	6.08	
					TA = +85°C		1.53	10.44	
					TA = +105°C		6.50	67.14	

(Notes and Remarks are listed on the next page.)

- Note 5.** Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and I_{WDT} when the watchdog timer is in operation.
- Note 6.** Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2 and I_{AADC} when the A/D converter operates in an operation mode or the HALT mode.
- Note 7.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and I_{LVD} when the LVD circuit is in operation.
- Note 8.** Current flowing during programming of the data flash.
- Note 9.** Current flowing during self-programming.
- Note 10.** For shift time to the SNOOZE mode, see **23.3.3 SNOOZE mode** in the RL78/G14 User's Manual.
- Note 11.** Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2 and I_{DAC} when the D/A converter operates in an operation mode or the HALT mode.
- Note 12.** Current flowing only to the comparator circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and I_{CMP} when the comparator circuit is in operation.
- Note 13.** A comparator and D/A converter are provided in products with 96 KB or more code flash memory.

Remark 1. f_{IL}: Low-speed on-chip oscillator clock frequency

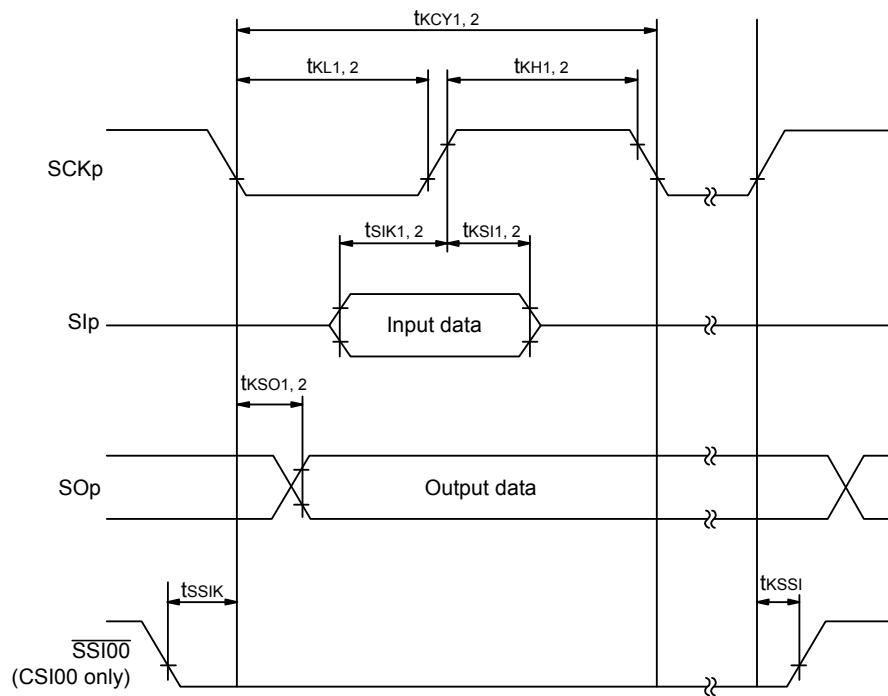
Remark 2. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

Remark 3. f_{CLOCK}: CPU/peripheral hardware clock frequency

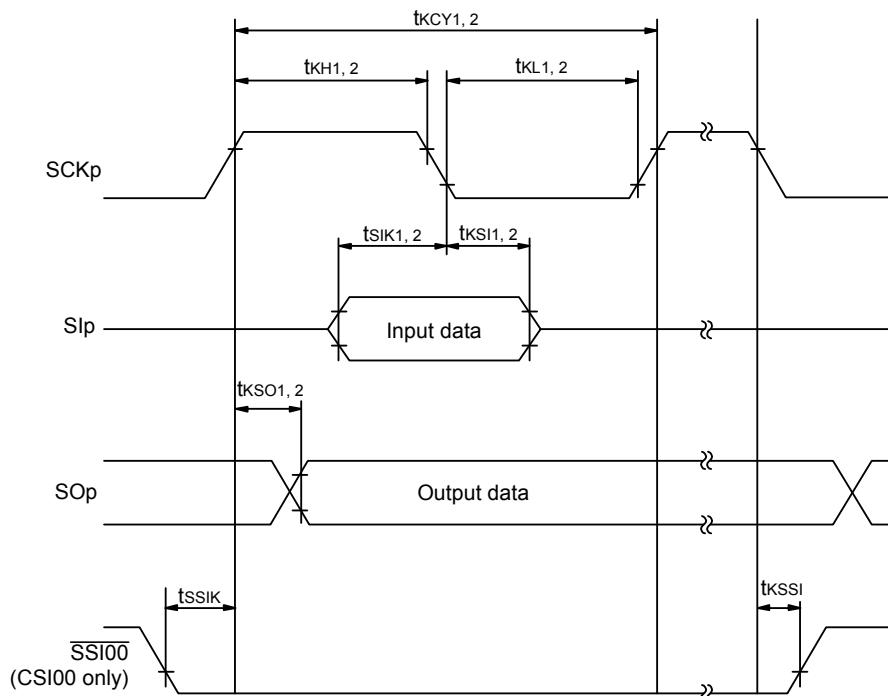
Remark 4. Temperature condition of the TYP. value is TA = 25°C

CSI mode serial transfer timing (during communication at same potential)

(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)

**CSI mode serial transfer timing (during communication at same potential)**

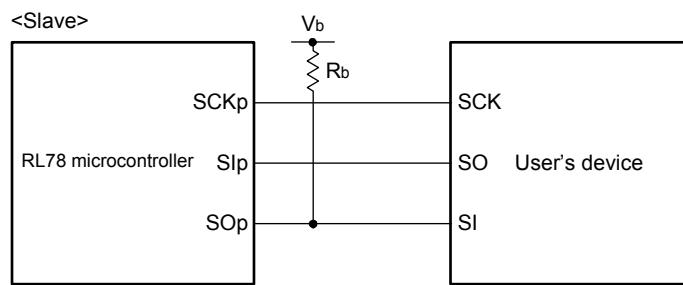
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 4.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the Slp pin and SCKp pin, and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and Vil, see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)



Remark 1. Rb[Ω]: Communication line (SOp) pull-up resistance, Cb[F]: Communication line (SOp) load capacitance, Vb[V]: Communication line voltage

Remark 2. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

Remark 3. fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn)).

m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))

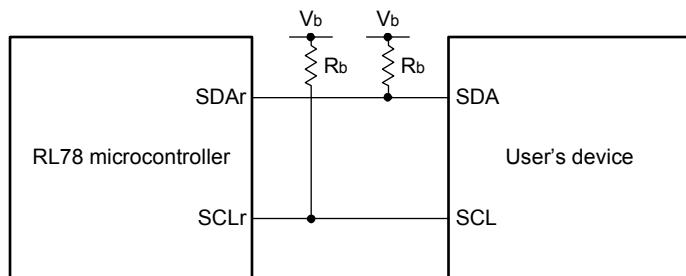
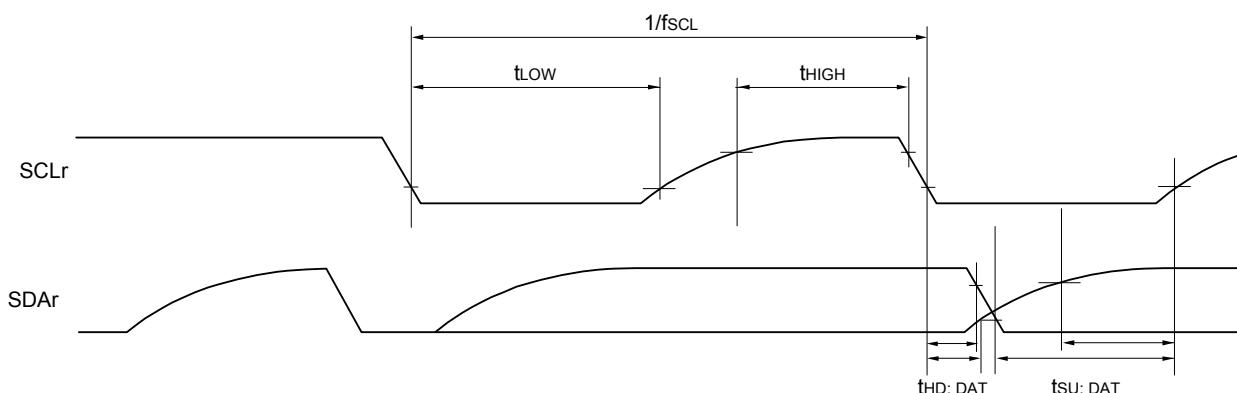
Remark 4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)(TA = -40 to +105°C, 2.4 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)

(1/2)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCL _r clock frequency	f _{SCL}	4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ		400 Note 1	kHz
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ		400 Note 1	kHz
		4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ		100 Note 1	kHz
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ		100 Note 1	kHz
		2.4 V ≤ EV _{DD0} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ		100 Note 1	kHz
Hold time when SCL _r = "L"	t _{LOW}	4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ	1200		ns
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ	1200		ns
		4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ	4600		ns
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ	4600		ns
		2.4 V ≤ EV _{DD0} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ	4650		ns
Hold time when SCL _r = "H"	t _{HIGH}	4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ	620		ns
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ	500		ns
		4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ	2700		ns
		2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ	2400		ns
		2.4 V ≤ EV _{DD0} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ	1830		ns

Simplified I²C mode connection diagram (during communication at different potential)**Simplified I²C mode serial transfer timing (during communication at different potential)**

Remark 1. $R_b[\Omega]$: Communication line (SDAr, SCLR) pull-up resistance, $C_b[F]$: Communication line (SDAr, SCLR) load capacitance, $V_b[V]$: Communication line voltage

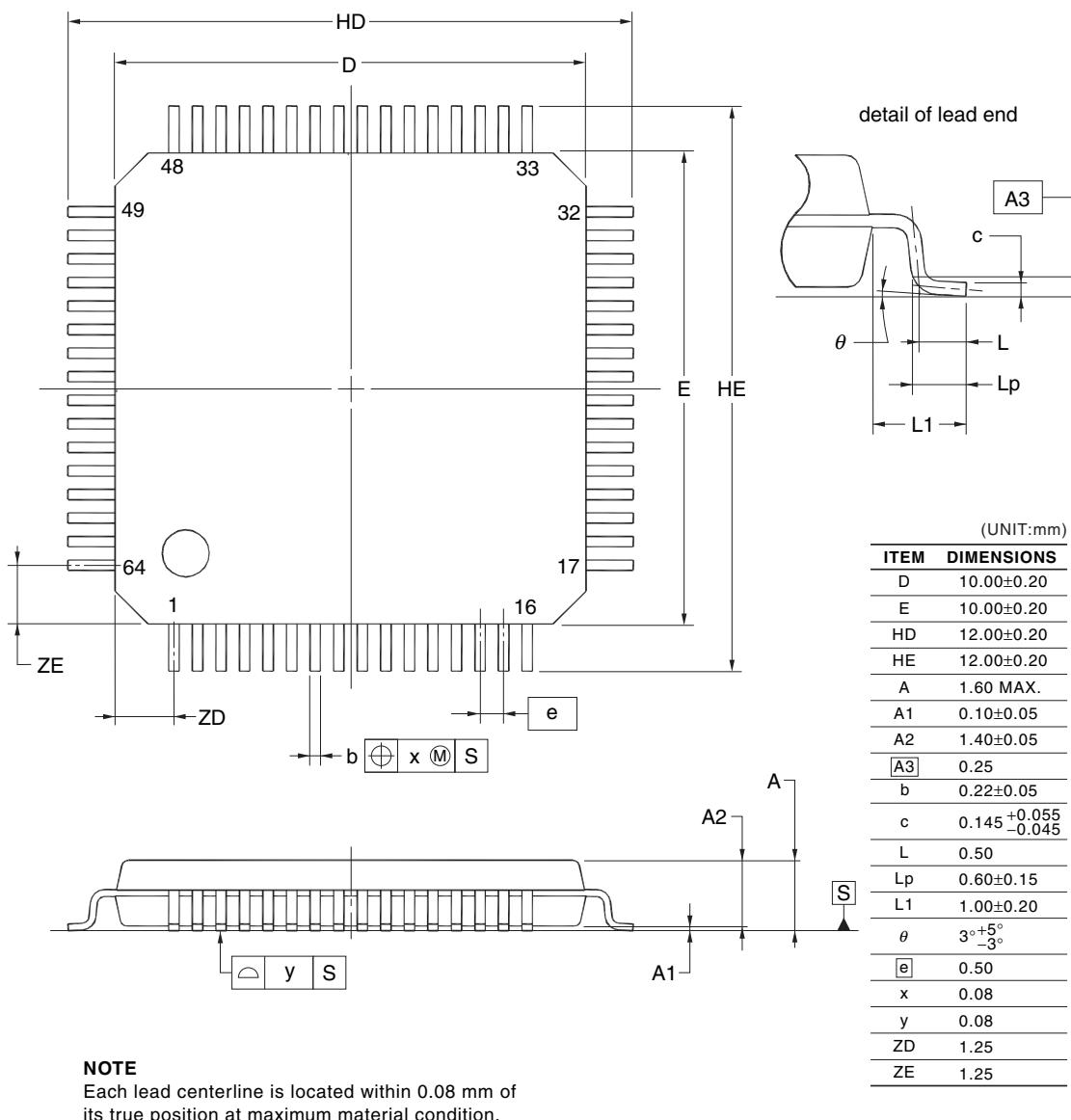
Remark 2. r: IIC number ($r = 00, 01, 10, 11, 20, 30, 31$), g: PIM, POM number ($g = 0, 1, 3$ to $5, 14$)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number ($m = 0, 1$), n: Channel number ($n = 0, 2$), mn = 00, 01, 02, 10, 12, 13)

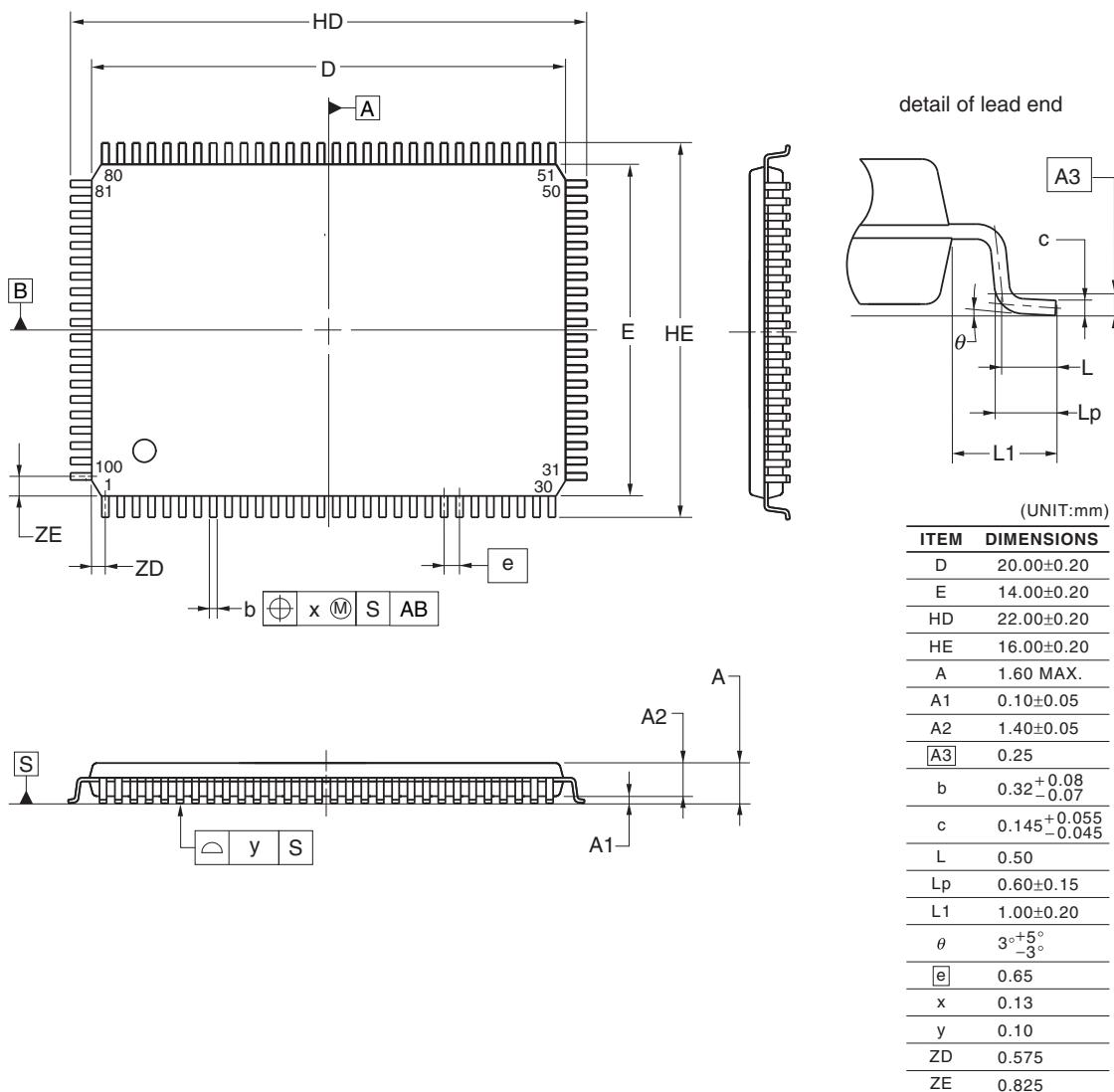
R5F104LCAF, R5F104LDAFB, R5F104LEAFB, R5F104LFAFB, R5F104LGAFB, R5F104LHAFB,
 R5F104LJAFB
 R5F104LCDFB, R5F104LDDFB, R5F104LEDFB, R5F104LFDFB, R5F104LGDFB, R5F104LHDFB,
 R5F104LJDFB
 R5F104LCGFB, R5F104LDGFB, R5F104LEGFB, R5F104LFGFB, R5F104LGGFB, R5F104LHGFB,
 R5F104LJGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP64-10x10-0.50	PLQP0064KF-A	P64GB-50-UEU-2	0.35



R5F104PFAFA, R5F104PGAFA, R5F104PHAFA, R5F104PJFAFA
 R5F104PFDFA, R5F104PGDFA, R5F104PHDFA, R5F104PJDFA
 R5F104PFGFA, R5F104PGGFA, R5F104PHGFA, R5F104PJGFA
 R5F104PKAFA, R5F104PLAFA
 R5F104PKGFA, R5F104PLGFA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP100-14x20-0.65	PLQP0100JC-A	P100GF-65-GBN-1	0.92



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